NSN 5961-00-533-6228

A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-533-6228 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 50.0 drain to gate voltage all transistor and 50.0 on-state drain to source voltage all transistor and 50.0 gate to source cutoff voltage all transistor **Current Rating Per Characteristic:** 50.00 milliamperes gate current all transistor **Power Rating Per Characteristic:** 500.0 milliwatts total device dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: